

vPolyTan™ Polymer Surface Mount Chip Capacitors, Compact, Leadframeless Molded Type



FEATURES

- Low ESR
- 100 % surge current tested
- Molded case available in 8 case codes including 0603 and 0805 footprint
- Lead (Pb)-free L-shaped face-down terminations
- 8 mm tape and reel packaging available per EIA-481 standard
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE
GREEN
(5-2008)

PERFORMANCE / ELECTRICAL CHARACTERISTICS

Operating Temperature: -55 °C to +105 °C
Capacitance Range: 1 µF to 330 µF
Capacitance Tolerance: ± 20 %
Voltage Rating: 6.3 V_{DC} to 35 V_{DC}

APPLICATIONS

- Decoupling, smoothing, filtering
- Bulk energy storage in wireless cards
- Infrastructure equipment
- Storage and networking
- Computer motherboards
- Smartphones and tablets

ORDERING INFORMATION

T58 TYPE	MM CASE CODE	106 CAPACITANCE	M CAPACITANCE TOLERANCE	6R3 DC VOLTAGE RATING	C TERMINATION / PACKAGING	0300 ESR
	See Ratings and Case Codes table.	This is expressed in picofarads. The first two digits are the significant figures. The third is the number of zeros to follow.	M = ± 20 %	This is expressed in volts. To complete the three-digit block, zeros precede the voltage rating. A decimal point is indicated by an "R" (6R3 = 6.3 V)	C = lead (Pb)-free solderable coating, 7" reel	Maximum 100 kHz ESR in mΩ

DIMENSIONS in inches [millimeters]

CASE CODE	EIA SIZE	H (MAX.)	L	W	P1	P2 (REF.)	C
MM	1608-09	0.035 [0.9]	0.063 ± 0.008 [1.6 ± 0.2]	0.033 ± 0.008 [0.85 ± 0.2]	0.020 ± 0.004 [0.5 ± 0.1]	0.024 [0.6]	0.024 ± 0.004 [0.6 ± 0.1]
M0	1608-10	0.039 [1.0]	0.063 ± 0.008 [1.6 ± 0.2]	0.033 ± 0.008 [0.85 ± 0.2]	0.020 ± 0.004 [0.5 ± 0.1]	0.024 [0.6]	0.024 ± 0.004 [0.6 ± 0.1]
W9	2012-09	0.035 [0.9]	0.079 ± 0.008 [2.0 ± 0.2]	0.049 ± 0.008 [1.25 ± 0.2]	0.020 ± 0.004 [0.5 ± 0.1]	0.039 [1.0]	0.035 ± 0.004 [0.9 ± 0.1]
W0	2012-10	0.039 [1.0]	0.079 ± 0.008 [2.0 ± 0.2]	0.049 ± 0.008 [1.25 ± 0.2]	0.020 ± 0.004 [0.5 ± 0.1]	0.039 [1.0]	0.035 ± 0.004 [0.9 ± 0.1]
A0	3216-10	0.039 [1.0]	0.126 ± 0.008 [3.2 ± 0.2]	0.063 ± 0.008 [1.6 ± 0.2]	0.031 ± 0.004 [0.8 ± 0.1]	0.063 [1.6]	0.047 ± 0.004 [1.2 ± 0.1]
AA	3216-18	0.071 [1.8]	0.126 ± 0.008 [3.2 ± 0.2]	0.063 ± 0.008 [1.6 ± 0.2]	0.031 ± 0.004 [0.8 ± 0.1]	0.063 [1.6]	0.047 ± 0.004 [1.2 ± 0.1]
B0	3528-10	0.039 [1.0]	0.138 ± 0.008 [3.5 ± 0.2]	0.110 ± 0.008 [2.8 ± 0.2]	0.031 ± 0.008 [0.8 ± 0.2]	0.077 [1.95]	0.094 ± 0.004 [2.4 ± 0.1]
BB	3528-20	0.079 [2.0]	0.138 ± 0.008 [3.5 ± 0.2]	0.110 ± 0.008 [2.8 ± 0.2]	0.031 ± 0.008 [0.8 ± 0.2]	0.077 [1.95]	0.094 ± 0.004 [2.4 ± 0.1]

RATINGS AND CASE CODES (ESR mΩ)						
μF	6.3 V	8.2 V	10 V	16 V	25 V	35 V
1						W9 (500)
4.7					W0 (500)	
10	MM (300, 500)					
22	MM (300, 500) / W9 (500)				BB (100, 150)	
47	M0 (300, 500) / W9 (150, 200, 300)	W0 (300, 500)	A0 (175)	BB (90, 200)		
100	A0 (100, 150)					

MARKING			
<p>Wx-Case</p>		<p>Mx-Case</p>	
<p>Ax-Case</p>		<p>Bx-Case</p>	
VOLTAGE CODE		CAPACITANCE CODE	
V	CODE	CAP, μF	CODE
6.3	J	1	A
8.2	k	4.7	S
10	A	10	α
16	C	22	j
25	E	47	s
35	V	100	Ā
		150	Ē



STANDARD RATINGS								
CAPACITANCE (μ F)	CASE CODE	PART NUMBER	MAX. DCL AT +25 °C (μ A)	MAX. DF AT +25 °C 120 Hz (%)	MAX. ESR AT +25 °C 100 kHz (m Ω)	MAX. RIPPLE, 100 kHz I _{RMS} (A)	HIGH TEMPERATURE LOAD TEMPERATURE (°C)	TIME (h)
6.3 V_{DC} AT +105 °C								
10	MM	T58MM106M6R3C0500	6.3	8	500	0.224	105	2000
10	MM	T58MM106M6R3C0300	6.3	8	300	0.289	105	2000
22	MM	T58MM226M6R3C0500	14	10	500	0.224	105	2000
22	MM	T58MM226M6R3C0300	14	10	300	0.289	105	2000
22	W9	T58W9226M6R3C0500	14	10	500	0.283	105	2000
47	M0 ⁽¹⁾	T58M0476M6R3C0500	30	14	500	0.224	85	2000
47	M0 ⁽¹⁾	T58M0476M6R3C0300	30	14	300	0.289	85	2000
47	W9	T58W9476M6R3C0300	30	10	300	0.365	105	1000
47	W9	T58W9476M6R3C0200	30	10	200	0.447	105	1000
47	W9	T58W9476M6R3C0150	30	10	150	0.516	105	1000
100	A0	T58A0107M6R3C0150	63	10	150	0.606	105	1000
100	A0	T58A0107M6R3C0100	63	10	100	0.742	105	1000
8.2 V_{DC} AT +105 °C								
47	W0	T58W0476M8R2C0500	39	10	500	0.283	105	1000
47	W0	T58W0476M8R2C0300	39	10	300	0.365	105	1000
10 V_{DC} AT +105 °C								
47	A0	T58A0476M010C0175	47	14	175	0.561	105	1000
16 V_{DC} AT +105 °C								
47	BB	T58BB476M016C0200	75	14	200	0.652	105	2000
47	BB	T58BB476M016C0090	75	14	90	0.972	105	2000
25 V_{DC} AT +105 °C								
4.7	W0	T58W0475M025C0500	23.5	10	500	0.283	105	1000
22	BB	T58BB226M025C0150	55	14	150	0.753	105	2000
22	BB	T58BB226M025C0100	55	14	100	0.850	105	2000
35 V_{DC} AT +105 °C								
1.0	W9	T58W9105M035C0500	3.5 ⁽²⁾	8	500	0.283	105	2000

Notes

- ⁽¹⁾ Humidity tests at 40 °C / 90 % RH 500 h, no voltage applied
- ⁽²⁾ Can be rated up to 38 V

RECOMMENDED VOLTAGE DERATING GUIDELINES	
CAPACITOR VOLTAGE RATING	OPERATING VOLTAGE
6.3	5.0
8.2	6.6
10	8.0
16	12.8
25	20
35	28



CAPACITANCE VS. FREQUENCY



IMPEDANCE AND ESR VS. FREQUENCY



POWER DISSIPATION

CASE CODE	MAXIMUM PERMISSIBLE POWER DISSIPATION AT +25 °C (W) IN FREE AIR
MM / M0	0.025
W9 / W0	0.040
A0	0.055
AA	0.075
B0	0.070
BB	0.085



STANDARD PACKAGING QUANTITY	
CASE CODE	UNITS PER 7" REEL
MM / M0	4000
W0	3000
W9	4000
A0	3000
AA	2000
B0	3000
BB	2000

PERFORMANCE CHARACTERISTICS			
ITEM	CONDITION	POST TEST PERFORMANCE	
Life test at +105 °C	2000 h application of rated voltage at 105 °C, MIL-STD-202 method 108	Capacitance change	Within ± 20 % of initial value
		Dissipation factor	Within initial limits
		Leakage current	Shall not exceed 300 % of initial limit
Humidity tests	At 60 °C / 90 % RH 500 h, no voltage applied	Capacitance change	-20 % to +40 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 300 % of initial limit
Stability at low and high temperatures	-55 °C	Capacitance change	Within -20 % to 0 % of initial value
		Dissipation factor	Shall not exceed 150 % of initial limit
		Leakage current	n/a
	25 °C	Capacitance change	Within ± 20 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Within initial limit
	105 °C	Capacitance change	Within -50 % to +30 % of initial value
		Dissipation factor	Within initial limits
		Leakage current	Shall not exceed 1000 % of initial limits
Surge voltage	85 °C, 1000 successive test cycles at 1.3 of rated voltage in series with a 1 kΩ resistor at the rate of 30 s ON, 30 s OFF	Capacitance change	Within ± 20 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 300 % of initial limit
Shock (specified pulse)	MIL-STD-202, method 213, condition I, 100 g peak	Capacitance change	Within ± 20 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 300 % of initial limit
Vibration	MIL-STD-202, method 204, condition D, 10 Hz to 2000 Hz 20 g peak	There shall be no mechanical or visual damage to capacitors post-conditioning.	
Shear test	Apply a pressure load of 5 N for 10 s ± 1 s horizontally to the center of capacitor side body	Capacitance change	Within ± 20 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 300 % of initial limit

PRODUCT INFORMATION	
Polymer Guide	www.vishay.com/doc?40076
Moisture Sensitivity	www.vishay.com/doc?40135
Infographic	www.vishay.com/doc?48084
Sample Board	www.vishay.com/doc?48073
FAQ	
Frequently Asked Questions	www.vishay.com/doc?42106



Guide for Tantalum Solid Electrolyte Chip Capacitors with Polymer Cathode

INTRODUCTION

Tantalum electrolytic capacitors are the preferred choice in applications where volumetric efficiency, stable electrical parameters, high reliability, and long service life are primary considerations. The stability and resistance to elevated temperatures of the tantalum/tantalum oxide/manganese dioxide system make solid tantalum capacitors an appropriate choice for today's surface mount assembly technology.

Vishay Sprague has been a pioneer and leader in this field, producing a large variety of tantalum capacitor types for consumer, industrial, automotive, military, and aerospace electronic applications.

Tantalum is not found in its pure state. Rather, it is commonly found in a number of oxide minerals, often in combination with Columbium ore. This combination is known as "tantalite" when its contents are more than one-half tantalum. Important sources of tantalite include Australia, Brazil, Canada, China, and several African countries. Synthetic tantalite concentrates produced from tin slags in Thailand, Malaysia, and Brazil are also a significant raw material for tantalum production.

Electronic applications, and particularly capacitors, consume the largest share of world tantalum production. Other important applications for tantalum include cutting tools (tantalum carbide), high temperature super alloys, chemical processing equipment, medical implants, and military ordnance.

Vishay Sprague is a major user of tantalum materials in the form of powder and wire for capacitor elements and rod and sheet for high temperature vacuum processing.

THE BASICS OF TANTALUM CAPACITORS

Most metals form crystalline oxides which are non-protecting, such as rust on iron or black oxide on copper. A few metals form dense, stable, tightly adhering, electrically insulating oxides. These are the so-called "valve" metals and include titanium, zirconium, niobium, tantalum, hafnium, and aluminum. Only a few of these permit the accurate control of oxide thickness by electrochemical means. Of these, the most valuable for the electronics industry are aluminum and tantalum.

Capacitors are basic to all kinds of electrical equipment, from radios and television sets to missile controls and automobile ignitions. Their function is to store an electrical charge for later use.

Capacitors consist of two conducting surfaces, usually metal plates, whose function is to conduct electricity. They are separated by an insulating material or dielectric. The dielectric used in all tantalum electrolytic capacitors is tantalum pentoxide.

Tantalum pentoxide compound possesses high-dielectric strength and a high-dielectric constant. As capacitors are being manufactured, a film of tantalum pentoxide is applied to their electrodes by means of an electrolytic process. The film is applied in various thicknesses and at various voltages and although transparent to begin with, it takes on different colors as light refracts through it. This coloring occurs on the tantalum electrodes of all types of tantalum capacitors.

Rating for rating, tantalum capacitors tend to have as much as three times better capacitance/volume efficiency than aluminum electrolytic capacitors. An approximation of the capacitance/volume efficiency of other types of capacitors may be inferred from the following table, which shows the dielectric constant ranges of the various materials used in each type. Note that tantalum pentoxide has a dielectric constant of 26, some three times greater than that of aluminum oxide. This, in addition to the fact that extremely thin films can be deposited during the electrolytic process mentioned earlier, makes the tantalum capacitor extremely efficient with respect to the number of microfarads available per unit volume. The capacitance of any capacitor is determined by the surface area of the two conducting plates, the distance between the plates, and the dielectric constant of the insulating material between the plates.

COMPARISON OF CAPACITOR DIELECTRIC CONSTANTS	
DIELECTRIC	ϵ DIELECTRIC CONSTANT
Air or vacuum	1.0
Paper	2.0 to 6.0
Plastic	2.1 to 6.0
Mineral oil	2.2 to 2.3
Silicone oil	2.7 to 2.8
Quartz	3.8 to 4.4
Glass	4.8 to 8.0
Porcelain	5.1 to 5.9
Mica	5.4 to 8.7
Aluminum oxide	8.4
Tantalum pentoxide	26
Ceramic	12 to 400K

In the tantalum electrolytic capacitor, the distance between the plates is very small since it is only the thickness of the tantalum pentoxide film. As the dielectric constant of the tantalum pentoxide is high, the capacitance of a tantalum capacitor is high if the area of the plates is large:

$$C = \frac{\epsilon A}{t}$$

where

C = capacitance

ϵ = dielectric constant

A = surface area of the dielectric

t = thickness of the dielectric

Tantalum capacitors contain either liquid or solid electrolytes. In solid electrolyte capacitors, a dry material (manganese dioxide) forms the cathode plate. A tantalum lead is embedded in or welded to the pellet, which is in turn connected to a termination or lead wire. The drawings show the construction details of the surface mount types of tantalum capacitors shown in this catalog.

SOLID ELECTROLYTE POLYMER TANTALUM CAPACITORS

Solid electrolyte polymer capacitors utilize sintered tantalum pellets as anodes. Tantalum pentoxide dielectric layer is formed on the entire surface of anode, which is further impregnated with highly conductive polymer as cathode system.

The conductive polymer layer is then coated with graphite, followed by a layer of metallic silver, which provides a conductive surface between the capacitor element and the outer termination (lead frame or other).

Molded chip polymer tantalum capacitor encases the element in plastic resins, such as epoxy materials. After assembly, the capacitors are tested and inspected to assure long life and reliability. It offers excellent reliability and high stability for variety of applications in electronic devices. Usage of conductive polymer cathode system provides very low equivalent series resistance (ESR), which makes the capacitors particularly suitable for high frequency applications.



TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T52



TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T54 / T59



POLYMER CAPACITORS - MOLDED CASE	
SERIES	T55
PRODUCT IMAGE	
TYPE	VPolyTan™, molded case, high performance polymer
FEATURES	High performance
TEMPERATURE RANGE	-55 °C to +105 °C
CAPACITANCE RANGE	3.3 μF to 1000 μF
VOLTAGE RANGE	2.5 V to 63 V
CAPACITANCE TOLERANCE	± 20 %
LEAKAGE CURRENT	0.1 CV
DISSIPATION FACTOR	8 % to 10 %
ESR	12 mΩ to 500 mΩ
CASE SIZES	J, P, A, T, B, Z, V, D
TERMINATION FINISH	Cases J, P: 100 % tin Case A: 100 % tin or Ni / Pd / Au Cases T, B, Z, V, D: Ni / Pd / Au

POLYMER CAPACITORS - LEADFRAMELESS MOLDED CASE				
SERIES	T52	T58	T59	T54
PRODUCT IMAGE				
TYPE	vPolyTan™ polymer surface mount chip capacitors, low profile, leadframeless molded type	vPolyTan™ polymer surface mount chip capacitors, compact, leadframeless molded type	vPolyTan™ polymer surface mount chip capacitors, low ESR, leadframeless molded type	vPolyTan™ polymer surface mount chip capacitors, low ESR, leadframeless molded type, hi-rel commercial off-the-shelf (COTS)
FEATURES	Low profile	Small case size	Multianode	Hi-rel COTS, multianode
TEMPERATURE RANGE	-55 °C to +105 °C	-55 °C to +105 °C	-55 °C to +105 °C	-55 °C to +125 °C
CAPACITANCE RANGE	47 μF to 1500 μF	1 μF to 330 μF	15 μF to 470 μF	15 μF to 470 μF
VOLTAGE RANGE	10 V to 35 V	6.3 V to 35 V	16 V to 75 V	16 V to 75 V
CAPACITANCE TOLERANCE	± 20 %	± 20 %	± 10 %, ± 20 %	± 20 %
LEAKAGE CURRENT	0.1 CV			
DISSIPATION FACTOR	10 %	8 % to 14 %	10 %	10 %
ESR	25 mΩ to 55 mΩ	50 mΩ to 500 mΩ	25 mΩ to 150 mΩ	25 mΩ to 150 mΩ
CASE SIZES	E5, M1	MM, M0, W0, W9, A0, AA, B0, BB	EE	EE
TERMINATION	100 % tin		100 % tin / lead	

MOLDED CAPACITORS, T55 TYPE
PLASTIC TAPE AND REEL PACKAGING DIMENSIONS in millimeters


TAPE WIDTH	8	12
A + 0 / - 3		Ø 180
B + 1 / 0		Ø 60
C ± 0.2		Ø 13
D ± 0.5		Ø 21
E ± 0.5		2.0
W ± 0.3	9.0	13.0

Note

- A reel diameter of 330 mm is also applicable

PLASTIC TAPE SIZE DIMENSIONS in millimeters


CASE CODE	A ± 0.2	B ± 0.2	W ± 0.3	F ± 0.1	E ± 0.1	P ₁ ± 0.1	t _{max.}
J	1.0	1.8	8.0	3.5	1.75	4.0	1.3
P	1.4	2.2	8.0	3.5	1.75	4.0	1.6
A	1.9	3.5	8.0	3.5	1.75	4.0	2.5
T	3.1	3.8	8.0	3.5	1.75	4.0	1.7
B	3.1	3.8	8.0	3.5	1.75	4.0	2.5
Z	4.8	7.7	12.0	5.5	1.75	8.0	2.6
V	4.8	7.7	12.0	5.5	1.75	8.0	2.6
D	4.8	7.7	12.0	5.5	1.75	8.0	3.4

Note

- A reel diameter of 330 mm is also applicable

LEADFRAMELESS MOLDED CAPACITORS, ALL TYPES



CARRIER TAPE DIMENSIONS in inches [millimeters]							
CASE CODE	TAPE SIZE	B ₁ (MAX.) ⁽¹⁾	D ₁ (MIN.)	F	K ₀ (MAX.)	P ₁	W
E5	12 mm	0.329 [8.35]	0.059 [1.5]	0.217 ± 0.002 [5.50 ± 0.05]	0.071 [1.8]	0.315 ± 0.004 [8.0 ± 0.10]	0.476 ± 0.008 [12.1 ± 0.20]
MM ⁽²⁾	8 mm	0.075 [1.91]	0.02 [0.5]	0.138 [3.5]	0.043 [1.10]	0.157 [4.0]	0.315 [8.0]
M1	12 mm	0.32 [8.2]	0.059 [1.5]	0.217 ± 0.002 [5.5 ± 0.05]	0.094 [2.39]	0.315 ± 0.04 [8.0 ± 1.0]	0.472 + 0.012 / - 0.004 [12.0 + 0.3 / - 0.10]
W9	8 mm	0.126 [3.20]	0.030 [0.75]	0.138 [3.5]	0.045 [1.15]	0.157 [4.0]	0.315 [8.0]
W0	8 mm	0.126 [3.20]	0.030 [0.75]	0.138 [3.5]	0.045 [1.15]	0.157 [4.0]	0.315 [8.0]
A0	8 mm	-	0.02 [0.5]	0.138 [3.5]	0.049 [1.25]	0.157 [4.0]	0.315 [8.0]
AA	8 mm	0.154 [3.90]	0.039 [1.0]	0.138 [3.5]	0.079 [2.00]	0.157 [4.0]	0.315 [8.0]
B0	12 mm	0.181 [4.61]	0.059 [1.5]	0.217 [5.5]	0.049 [1.25]	0.157 [4.0]	0.315 [8.0]
BB	8 mm	0.157 [4.0]	0.039 [1.0]	0.138 [3.5]	0.087 [2.22]	0.157 [4.0]	0.315 [8.0]
EE	12 mm	0.32 [8.2]	0.059 [1.5]	0.217 ± 0.002 [5.5 ± 0.05]	0.175 [4.44]	0.315 ± 0.04 [8.0 ± 1.0]	0.472 + 0.012 / - 0.004 [12.0 + 0.3 / - 0.10]

Notes

- (1) For reference only
 (2) Standard packaging of MM case is with paper tape. Plastic tape is available per request

PAPER TAPE AND REEL PACKAGING DIMENSIONS in inches [millimeters]											
<p>The diagram illustrates the dimensions of a paper tape used for reel packaging. It shows a cross-section of the tape with a top cover tape and a bottom cover tape. The tape is fed from left to right, as indicated by the 'USER FEED DIRECTION' arrow. Key dimensions include: <ul style="list-style-type: none"> A₀: Anode width B₀: Cavity width D₀: Hole diameter P₀: Pitch between holes P₁: Pitch between cavities P₂: Pitch between anodes E: Hole offset F: Anode offset W: Total tape width T: Tape thickness G: Anode offset from cavity center line E₁, E₂: Hole offset from cavity center line A note indicates a cumulative tolerance of ± 0.2 mm over 10 pitches on the tape. </p>											
CASE SIZE	TAPE SIZE	A ₀	B ₀	D ₀	P ₀	P ₁	P ₂	E	F	W	T
MM	8 mm	0.041 ± 0.002 [1.05 ± 0.05]	0.071 ± 0.002 [1.8 ± 0.05]	0.06 ± 0.004 [1.5 ± 0.1]	0.157 ± 0.004 [4.0 ± 0.1]	0.157 ± 0.004 [4.0 ± 0.1]	0.079 ± 0.002 [2.0 ± 0.05]	0.069 ± 0.004 [1.75 ± 0.1]	0.0138 ± 0.002 [3.5 ± 0.05]	0.315 ± 0.008 [8.0 ± 0.2]	0.037 ± 0.002 [0.95 ± 0.05]
M0	8 mm	0.049 ± 0.002 [1.25 ± 0.05]	0.081 ± 0.002 [2.05 ± 0.05]	0.06 ± 0.004 [1.5 ± 0.1]	0.157 ± 0.004 [4.0 ± 0.1]	0.157 ± 0.004 [4.0 ± 0.1]	0.079 ± 0.002 [2.0 ± 0.05]	0.069 ± 0.004 [1.75 ± 0.1]	0.0138 ± 0.002 [3.5 ± 0.05]	0.315 ± 0.008 [8.0 ± 0.2]	0.041 ± 0.002 [1.05 ± 0.05]

Note

- (1) A₀, B₀ are determined by the maximum dimensions to the ends of the terminals extending from the component body and / or the body dimensions of the component. The clearance between the ends of the terminals or body of the component to the sides and depth of the cavity (A₀, B₀) must be within 0.002" (0.05 mm) minimum and 0.020" (0.50 mm) maximum. The clearance allowed must also prevent rotation of the component within the cavity of not more than 20°

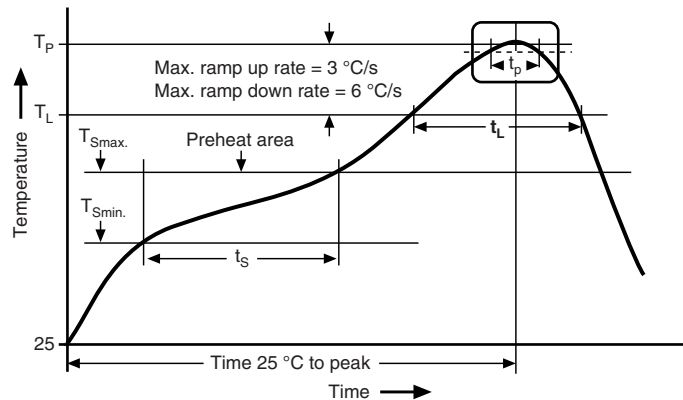
PACKING AND STORAGE

Polymer capacitors meet moisture sensitivity level rating (MSL) of 3 or 4 as specified in IPC/JEDEC® J-STD-020 and are dry packaged in moisture barrier bags (MBB) per J-STD-033. Standard Ratings table defines MSL level for each particular family. Level 3 specifies a floor life (out of bag) of 168 hours and level 4 specifies a floor life of 72 hours at 30 °C maximum and 60 % relative humidity (RH). Unused capacitors should be re-sealed in the MBB with fresh desiccant. A moisture strip (humidity indicator card) is included in the bag to assure dryness. To remove excess moisture, capacitors can be dried at 40 °C (standard “dry box” conditions).

For detailed recommendations please refer to J-STD-033.

RECOMMENDED REFLOW PROFILES

Vishay recommends no more than 3 cycles of reflow in accordance with J-STD-020.



PROFILE FEATURE	SnPb EUTECTIC ASSEMBLY	LEAD (Pb)-FREE ASSEMBLY
PREHEAT AND SOAK		
Temperature min. ($T_{Smin.}$)	100 °C	150 °C
Temperature max. ($T_{Smax.}$)	150 °C	200 °C
Time (t_s) from ($T_{Smin.}$ to $T_{Smax.}$)	60 s to 120 s	60 s to 120 s
RAMP UP		
Ramp-up rate (T_L to T_p)	3 °C/s maximum	
Liquidus temperature (T_L)	183 °C	217 °C
Time (t_L) maintained above T_L	60 s to 150 s	
Peak package body temperature (T_p) max.	Depends on type and case - see table below	
Time (t_p) within 5 °C of the peak max. temperature	20 s	5 s
RAMP DOWN		
Ramp-down rate (T_p to T_L)	6 °C/s maximum	
Time from 25 °C to peak temperature	6 min maximum	8 min maximum

PEAK PACKAGE BODY TEMPERATURE (T_p) MAXIMUM

TYPE	CASE CODE	PEAK PACKAGE BODY TEMPERATURE (T_p) MAX.	
		SnPb EUTECTIC ASSEMBLY	LEAD (Pb)-FREE ASSEMBLY
T55	J, P, A, T, B, Z, V, D	n/a	260 °C
T52	E5, M1		260 °C
T58	MM, M0, W9, W0, A0, AA, B0, BB		260 °C
T59	EE	220 °C	250 °C
T54	EE	220 °C	250 °C

Notes

- T52, T55, and T58 capacitors are process sensitive. PSL classification to JEDEC J-STD-075: R4G
- T54 and T59 capacitors with 100 % tin termination are process sensitive. PSL classification to JEDEC J-STD-075: R6G

MOLDED CAPACITORS, T55 TYPE

PAD DIMENSIONS in millimeters						
CASE / DIMENSIONS	CAPACITOR SIZE		PAD DIMENSIONS			
	L	W	G (max.)	Z (min.)	X (min.)	Y (Ref.)
J	1.6	0.8	0.7	2.5	1.0	0.9
P	2.0	1.25	0.5	2.6	1.2	1.05
A	3.2	1.6	1.1	3.8	1.5	1.35
T / B	3.5	2.8	1.4	4.1	2.7	1.35
Z / V / D	7.3	4.3	4.1	8.2	2.9	2.05

LEADFRAMELESS MOLDED CAPACITORS, ALL TYPES

PAD DIMENSIONS in inches [millimeters]					
FAMILY	CASE CODE	A (NOM.)	B (MIN.)	C (NOM.)	D (MIN.)
T52	E5	0.094 [2.40]	0.073 [1.85]	0.187 [4.75]	0.333 [8.45]
	M1	0.161 [4.10]	0.073 [1.85]	0.187 [4.75]	0.333 [8.45]
T58	MM, M0	0.024 [0.61]	0.027 [0.70]	0.025 [0.64]	0.080 [2.03]
	W0, W9	0.035 [0.89]	0.029 [0.74]	0.041 [1.05]	0.099 [2.52]
	AA, A0, A2	0.047 [1.19]	0.042 [1.06]	0.065 [1.65]	0.148 [3.76]
	BB, B0	0.094 [2.39]	0.044 [1.11]	0.072 [1.82]	0.159 [4.03]
T59 / T54	EE	0.209 [5.30]	0.098 [2.50]	0.169 [4.30]	0.366 [9.30]

GUIDE TO APPLICATION

- AC Ripple Current:** the maximum allowable ripple current shall be determined from the formula:

$$I_{RMS} = \sqrt{\frac{P}{R_{ESR}}}$$

where,

P = power dissipation in W at +45 °C as given in the tables in the product datasheets.

R_{ESR} = the capacitor equivalent series resistance at the specified frequency.

- AC Ripple Voltage:** the maximum allowable ripple voltage shall be determined from the formula:

$$V_{RMS} = Z \sqrt{\frac{P}{R_{ESR}}}$$

or, from the formula:

$$V_{RMS} = I_{RMS} \times Z$$

where,

P = power dissipation in W at +45 °C as given in the tables in the product datasheets.

R_{ESR} = The capacitor equivalent series resistance at the specified frequency.

Z = The capacitor impedance at the specified frequency.

- The tantalum capacitors must be used in such a condition that the sum of the working voltage and ripple voltage peak values does not exceed the rated voltage as shown in figure below.



- Temperature Derating:** power dissipation is affected by the heat sinking capability of the mounting surface. If these capacitors are to be operated at temperatures above +45 °C, the permissible ripple current (or voltage) shall be calculated using the derating coefficient as shown in the table below:

MAXIMUM RIPPLE CURRENT TEMPERATURE DERATING FACTOR	
≤ 45 °C	1.0
55 °C	0.8
85 °C	0.6
105 °C	0.4

- Reverse Voltage:** the capacitors are not intended for use with reverse voltage applied. However, they are capable of withstanding momentary reverse voltage peaks, which must not exceed the following values:
At 25 °C: 10 % of the rated voltage or 1 V, whichever is smaller.
At 85 °C: 5 % of the rated voltage or 0.5 V, whichever is smaller.
At 105 °C: 3 % of the rated voltage or 0.3 V, whichever is smaller.

- Mounting Precautions:**

- Limit Pressure on Capacitor Installation with Mounter:** pressure must not exceed 4.9 N with a tool end diameter of 1.5 mm when applied to the capacitors using an absorber, centering tweezers, or similar (maximum permitted pressurization time: 5 s). An excessively low absorber setting position would result in not only the application of undue force to the capacitors but capacitor and other component scattering, circuit board wiring breakage, and / or cracking as well, particularly when the capacitors are mounted together with other chips having a height of 1 mm or less.

- Flux Selection**

- 5.2.1 Select a flux that contains a minimum of chlorine and amine.
- 5.2.2 After flux use, the chlorine and amine in the flux remain must be removed.

- Cleaning After Mounting:** the following solvents are usable when cleaning the capacitors after mounting. Never use a highly active solvent.

- Halogen organic solvent (HCFC225, etc.)
- Alcoholic solvent (IPA, ethanol, etc.)
- Petroleum solvent, alkali saponifying agent, water, etc.

Circuit board cleaning must be conducted at a temperature of not higher than 50 °C and for an immersion time of not longer than 30 minutes. When an ultrasonic cleaning method is used, cleaning must be conducted at a frequency of 48 kHz or lower, at an vibrator output of 0.02 W/cm³, at a temperature of not higher than 40 °C, and for a time of 5 minutes or shorter.

Notes

- Care must be exercised in cleaning process so that the mounted capacitor will not come into contact with any cleaned object or the like or will not get rubbed by a stiff brush or similar. If such precautions are not taken particularly when the ultrasonic cleaning method is employed, terminal breakage may occur.
- When performing ultrasonic cleaning under conditions other than stated above, conduct adequate advance checkout.



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